

Data Sheet January 2000 File Number 3545.3

### 100A, 1200V Ultrafast Diode

The RURU100120 is an ultrafast diode with soft recovery characteristics ( $t_{rr}$  < 125ns). It has low forward voltage drop and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

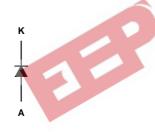
Formally developmental type TA49020.

# **Ordering Information**

PART NUMBER	PACKAGE	BRAND
RURU100120	TO-218	URU100120

NOTE: When ordering, use the entire part number.

# Symbol



#### **Features**

Ultrafast with Soft Recovery	<125ns
Operating Temperature	175 <sup>0</sup> C
Reverse Voltage	1200V

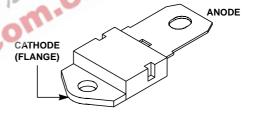
- · Avalanche Energy Rated
- · Planar Construction

# **Applications**

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

### **Packaging**

JEDEC STYLE SINGLE LEAD TO-218



Absolute Maximum Ratings T <sub>C</sub> = 25°C		
	RURU100120	UNITS
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	1200	V
Working Peak Reverse Voltage	1200	V
DC Blocking VoltageV <sub>R</sub>	1200	V
Average Rectified Forward Current	100	Α
$(T_C = 50^{\circ}C)$		
Repetitive Peak Surge Current	200	Α
(Square Wave, 20kHz)		
Nonrepetitive Peak Surge Current	500	Α
(Halfwave, 1 Phase, 60Hz)		
Maximum Power Dissipation	210	W
Avalanche Energy (See Figure 7 and 8)	50	mJ
Operating and Storage Temperature	-65 to 175	оС

#### RURU100120

### **Electrical Specifications** $T_C = 25^{\circ}C$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 100A	-	-	2.1	V
	I <sub>F</sub> = 100A, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	1.9	V
I <sub>R</sub>	V <sub>R</sub> = 1200V	-	-	250	μА
	V <sub>R</sub> = 1200V, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	2	mA
t <sub>rr</sub>	$I_F = 1A$ , $dI_F/dt = 100A/\mu s$	-	-	125	ns
	I <sub>F</sub> = 100A, dI <sub>F</sub> /dt = 100A/μs	-	-	200	ns
ta	I <sub>F</sub> = 100A, dI <sub>F</sub> /dt = 100A/μs	-	90	-	ns
t <sub>b</sub>	I <sub>F</sub> = 100A, dI <sub>F</sub> /dt = 100A/μs	-	65	-	ns
$R_{ heta JC}$		-	-	0.71	°C/W

#### **DEFINITIONS**

 $V_F$  = Instantaneous forward voltage (pw = 300 $\mu$ s, D = 2%).

 $I_R$  = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 6), summation of  $t_a$  +  $t_b$ .

 $t_a$  = Time to reach peak reverse current (See Figure 6).

 $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 6).  $I_{RM}$  = Thermal resistance junction to case.

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

# Typical Performance Curves

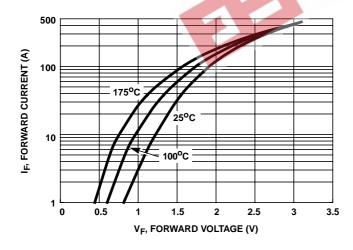


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

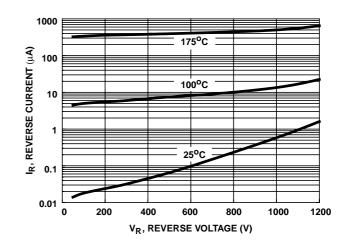
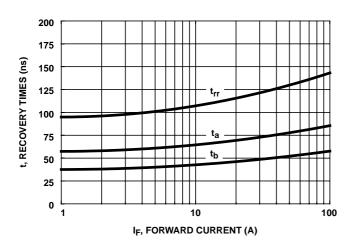


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

# Typical Performance Curves (Continued)



IF(AV), AVERAGE FORWARD CURRENT (A) 100 80 DC SQ. WAVE 60 40 20 25 50 150 175 T<sub>C</sub>, CASE TEMPERATURE (°C)

FIGURE 3. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT

FIGURE 4. CURRENT DERATING CURVE

### Test Circuits and Waveforms

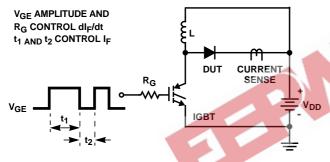


FIGURE 5. t<sub>rr</sub> TEST CIRCUIT

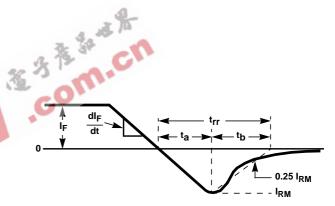


FIGURE 6.  $t_{rr}$  WAVEFORMS AND DEFINITIONS

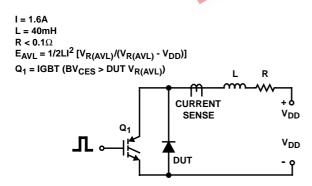


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

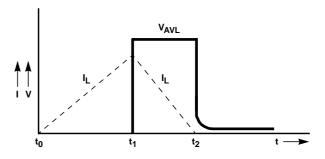


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE **WAVEFORMS** 

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